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A Comprehensive Review on Titanium Dioxide (TiO_2) Thin Films for Gas Sensing Applications: Fundamental Mechanisms, Research Gaps, And Processing-Driven Advancement

Sourabh V. Gaikwad[1], Nayan S. Nagargoje[2], Shaikh Mohd. Waseem[3]
[1]Department of Physics, Dalit Mitra Kadam Guruji Vidnyan Mahavidyalaya, Mangalwedha, MH India
[2]Department of Physics & Electronics, Maulana Azad College of Arts, Science & Commerce, Aurangabad, MH, India

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Correspondence Address:
Sourabh V. Gaikwad
Department of Physics, Dalit Mitra Kadam Guruji Vidnyan Mahavidyalaya, Mangalwedha, MH, India
Email: sourabhphy2112@gmail.com

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Abstract

Titanium dioxide (TiO_2) is one of the most extensively investigated metal oxide semiconductors for gas sensing applications due to its chemical stability, non-toxicity, wide band gap, and compatibility with high-temperature operation. Despite decades of research, the translation of TiO_2-based gas sensors into reliable and reproducible devices remains limited by fundamental issues such as anatase-to-rutile phase transformation, thermally induced grain growth, insufficient control over surface and bulk conduction, and thickness-dependent sensing behavior. This review presents a detailed and critical synthesis of three peer-reviewed research papers, supported by established metal oxide theory, to systematically analyze these challenges. Particular emphasis is placed on identifying unresolved research gaps and evaluating how microstructure control, phase stabilization, and ultrathin film engineering contribute to improved gas sensing performance.

Keywords: *Titanium dioxide, metal oxide semiconductors, gas sensing mechanism, anatase stability, ultrathin films, microstructure engineering*

Introduction

Metal oxide semiconductor gas sensors function on the principle that adsorption and surface reaction of gas molecules alter the charge carrier concentration within the sensing layer. In n-type oxides such as TiO_2, oxygen species adsorbed on the surface extract electrons from the conduction band, forming a surface depletion region. Exposure to reducing or oxidizing gases modifies this depletion layer, resulting in measurable changes in electrical resistance. Titanium dioxide has attracted particular attention because of its excellent chemical durability, resistance to corrosion, and ability to operate under harsh environmental conditions. However, the sensing behavior of TiO_2 is highly sensitive to its crystal phase, microstructure, defect chemistry, and thickness. Therefore, controlling these parameters is essential for developing reliable and high-performance gas sensors.

Fundamental Properties of TiO_2 Relevant to Gas Sensing

TiO_2 exists mainly in anatase and rutile polymorphs, each possessing distinct structural and electronic properties. Anatase TiO_2 is characterized by a higher density of surface defects, larger specific surface area, and enhanced adsorption activity, making it favorable for gas sensing. Rutile TiO_2, on the other hand, is thermodynamically more stable but generally exhibits lower surface reactivity. The electrical conductivity of TiO_2 is dominated by oxygen vacancies and Ti^{3+} defect states, which act as donor levels. According to metal oxide theory, gas sensing performance is governed by the interaction between these defect states and surface-adsorbed species. Consequently, phase transformation and grain growth directly influence sensing behavior by modifying defect density and surface area.

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Research Gaps in TiO_2-Based Gas Sensors

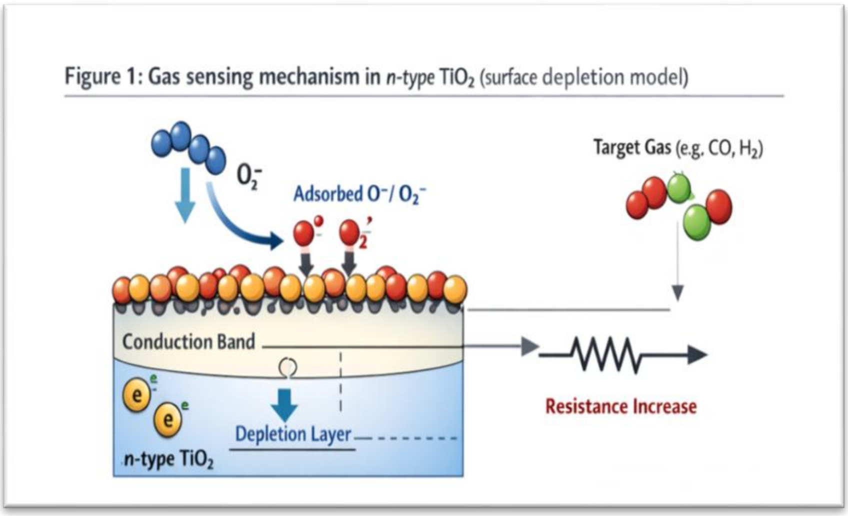
Despite extensive investigation, several critical research gaps persist:

1. **Phase Instability of Anatase TiO_2**

Anatase-to-rutile phase transformation typically occurs during high-temperature processing or prolonged sensor operation. This transformation is accompanied by grain coarsening and reduction in surface area, leading to degradation of sensing performance.

2. **Grain Growth and Loss of Surface Activity**

Thermal treatments required for film densification often induce excessive grain growth, which reduces the density of active adsorption sites.



3. **Response and Recovery Limitations**

Many TiO_2 sensors exhibit slow response and recovery times due to limited gas diffusion pathways and poorly controlled porosity.

4. **Thickness-Dependent Charge Transport**

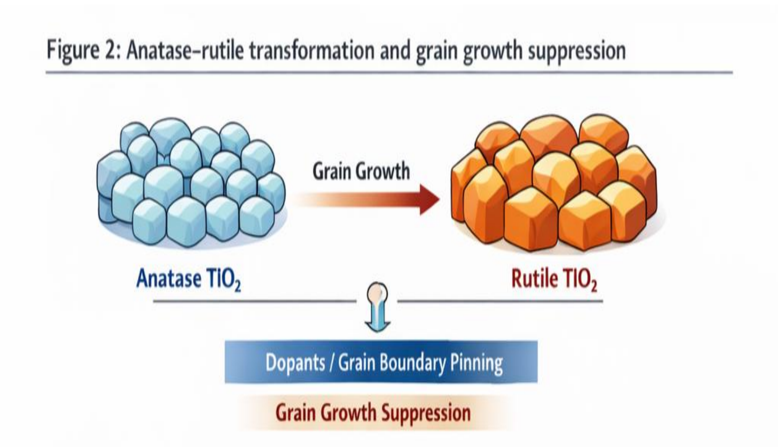
Conventional thick films do not fully exploit surface-controlled conduction. When film thickness exceeds the Debye length, bulk conduction dominates, reducing sensitivity.

5. **Structure–Property–Performance Relationship in TiO_2 Gas Sensors**

Gas sensing mechanism in n-type TiO_2

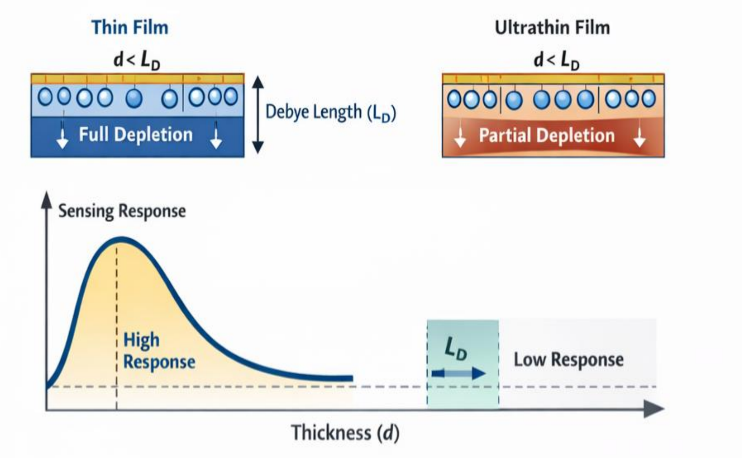
The gas sensing behavior of n-type TiO_2 is governed by surface adsorption of oxygen species and the formation of a surface depletion layer. Adsorbed oxygen captures electrons from the conduction band, increasing resistance. Exposure to reducing gases releases these electrons, leading to measurable resistance modulation.

Phase transformation and microstructural effects



Anatase and rutile phases of TiO_2 exhibit distinct sensing characteristics. Anatase provides higher surface reactivity, whereas rutile offers thermal stability. Mixed-phase systems benefit from interfacial charge transfer and suppressed grain growth.

Figure 3: Thickness effect and Debye length concept in ultrathin films



Thickness and Debye length consideration

When the sensing layer thickness approaches the Debye length, full depletion occurs, resulting in maximum sensitivity. Thickness optimization is therefore crucial for high-performance gas sensors.

Addressing the Research Gaps: Insights from Reviewed Studies

1. **Hydrothermal Microstructure Control and Thermal Stability**

Hydrothermal treatment of alkoxide-derived TiO_2 gels significantly suppresses crystallite growth and delays anatase-to-rutile transformation. The study revealed that phase stability is influenced not only by crystallite size but also by surface energetics and preparation conditions, particularly solution pH. Stabilized anatase retained its structure even after high-temperature calcination, preserving surface activity essential for gas sensing.

From a gas sensing perspective, the formation of mesoporous structures improved gas diffusion and enhanced response transients, directly addressing the issue of slow sensor dynamics.

2. **Understanding Phase Stability Beyond Grain Size**

A key contribution of the hydrothermal study is the demonstration that suppression of grain growth does not automatically prevent phase transformation. This finding fills an important knowledge gap by decoupling crystallite size effects from phase stability, emphasizing the role of surface chemistry and defect distribution.

3. **Ultrathin TiO_2 Films and Thickness Optimization**

Ultrathin TiO_2 films with thickness below 20 nm deposited by reactive magnetron sputtering. Their work established reliable characterization of ultrathin films using spectroscopic ellipsometry and scanning probe microscopy. Annealing transformed amorphous films into polycrystalline anatase while preserving nanoscale thickness.

When film thickness approaches the Debye length, the entire film becomes sensitive to surface reactions. This condition enhances gas sensitivity and reduces response time, highlighting thickness reduction as a powerful strategy for sensor optimization.

4. **Thickness-Controlled Gas Sensitivity**

The effect of TiO_2 film thickness on gas sensing performance using atomic layer deposition. Their results clearly demonstrated that thinner films exhibit enhanced gas sensitivity due to increased modulation of charge carriers by surface reactions. This study provides direct experimental validation of thickness-dependent sensing models.

Comparative Analysis of Processing Strategies

Hydrothermal processing and ultrathin film deposition represent complementary approaches to sensor optimization. Hydrothermal treatment enhances thermal and structural stability, while ultrathin film engineering maximizes surface sensitivity. Together, these strategies illustrate that no single parameter governs sensing behavior; rather, optimized performance requires simultaneous control of phase, microstructure, and thickness.

Research Gap	Limitation	Proposed Strategy	Impact
Room-temperature operation	High activation energy	Noble metal doping	Lower operating temperature
Poor selectivity	Similar gas responses	Heterostructures	Enhanced selectivity
Thermal instability	Grain growth	Grain boundary pinning	Improved stability
Low sensitivity	Thick films	Debye length matching	Higher response

Table 1 summarizes the relationship between research gaps and solutions proposed by the reviewed studies.

Parameter	Anatase	Rutile	Mixed Phase
Surface activity	High	Moderate	Very high
Grain size	Small	Large	Controlled
Thermal stability	Moderate	High	High
Gas sensing response	High	Moderate	Superior

Table 2. Comparative analysis of TiO_2 phase and microstructure

Method	Structure	Thickness Control	Sensing Relevance
Sol–gel	Porous films	Moderate	Cost-effective sensors
Sputtering	Dense films	Excellent	Reproducible performance
CVD	Crystalline films	Excellent	High-temp stability
ALD	Ultrathin films	Atomic-scale	Debye-length matched sensing

Table 3. Processing routes and gas sensing relevance

Implications for Practical Gas Sensor Design

The insights gained from these studies have important implications for device fabrication. Stabilization of anatase phase enables reliable high-temperature operation, while thickness optimization allows for low-power and fast-response sensors. Integrating these approaches could lead to sensors with improved reproducibility and long-term stability.

Future Research Directions

Future work should focus on combining hydrothermally stabilized TiO_2 nanostructures with ultrathin architectures, exploring defect engineering strategies, and conducting long-term stability tests under realistic operating conditions. Development of unified transport models incorporating surface adsorption, grain boundary effects, and thickness-dependent conduction is also necessary.

Conclusion

This expanded review provides a comprehensive and original synthesis of three peer-reviewed studies addressing fundamental research gaps in TiO_2-based gas sensors. By systematically linking metal oxide theory with experimental advancements, the review highlights phase stability, microstructure control, and thickness optimization as critical design parameters. The insights presented here contribute to the development of reliable and application-ready TiO_2 gas sensing devices.

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Conflicts of interest

The authors declare that there are no conflicts of interest regarding the publication of this paper.

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